

READ2353J

Ultra-Small Low Voltage Drive Input Output Full Range

CMOS Dual Operational Amplifier

R03DS0161EJ0100

Rev.1.00

2022.5.12

$V_{IO} \leq \pm 6\text{mV}$, SR=0.35V/ μs , GBW=550KHz

Description

The READ2353J is input and output full range dual CMOS Operational Amplifier realizing low voltage and low current consumption operation. This IC can be used in minimum operating supply voltage from 1.8V, and in wide ambient temperature range from -40°C to +125°C.

Available in ultra-small 8 pins TSSOP packages.

Features

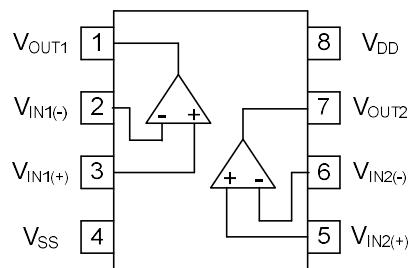
- AEC-Q100 Compliant
- Low voltage single supply operation $V_{DD} = 1.8\text{V}$ to 5.5V
- Low input offset voltage $V_{IO} \leq \pm 6.0\text{mV}$
- Low input bias current $I_B \leq (1\text{pA})$.
- Wide output voltage range $V_{OUT} : V_{SS}+0.1\text{V}$ to $V_{DD}-0.1\text{V}$ (@ $I_O=1\text{mA}$)
- Supply current (per channel) $I_{DD} = 40\mu\text{A}$ Typ.
- High slew rate SR = 0.35V/ μs Typ.

() reference value of design

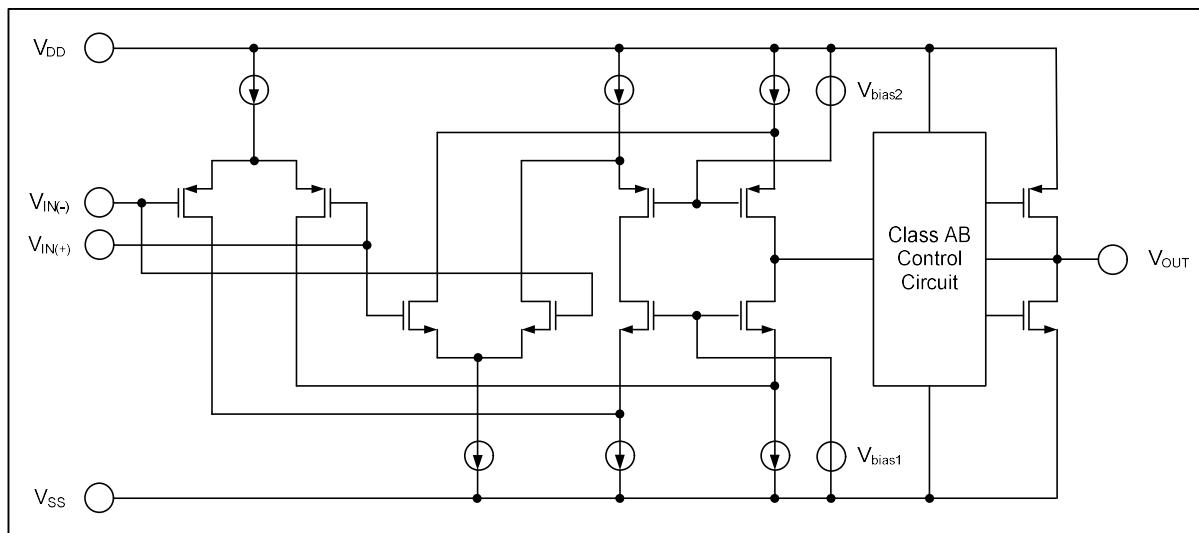
Product Line-up

Type name	Product type quality level	Package
READ2353JSP	Low consumption current with high quality level	8 pins plastic TSSOP

Pin Arrangement



Equivalent Circuit (per one channel)



Absolute Maximum Ratings

 $< T_A = 25^\circ\text{C} >$

Items	Symbol	Ratings	Unit
Supply voltage ^{Note.1}	V_{DD}	-0.3 to +6.5	V
Differential input voltage	V_{ID}	$-V_{DD}$ to $+V_{DD}$	V
Input voltage ^{Note.2}	V_I	-0.3 to $V_{DD} + 0.3$	V
Maximum output current	I_O	10	mA
Power dissipation ^{Note.3}	P_T	440	mW
Junction temperature	T_j	+150	$^\circ\text{C}$
Operating temp. range	T_A	-40 to +125	$^\circ\text{C}$
Storage temp. range	T_{stg}	-55 to +150	$^\circ\text{C}$

Note 1. Please take note that reverse connection of a power supply may cause destruction.

2. Stresses above these ratings may cause permanent damage such as characteristics degradation or destruction. Please do not exceed voltage below of GND-0.3V as it is bottom limit. In addition, operation amplifier is operated as normal when input voltage for electrical characteristics is in common mode input voltage range.

3. The value is measured under mounted on a glass epoxy base board (size 100mm×100mm, 1mm thickness, copper foiled surface base board area with 15% solid pattern).

Note that restrictions will be made to the following conditions for each product, and the derating ratio depending on the operating ambient temperature.

READ2353JSP: Derate at -5.5 mW/ $^\circ\text{C}$ when $T_A > 69^\circ\text{C}$

(Junction – ambient thermal resistance $R_{th(J-A)} = 183^\circ\text{C/W}$)

Electrical Characteristics< $V_{DD}=3.3V$, $T_A=25^\circ C$ >

Items	Symbol	MIN.	TYP.	MAX.	Unit	Test Condition
Supply voltage	$V_{DD} - V_{SS}$	1.8		5.5	V	
Input offset voltage	V_{IO}			± 6.0	mV	
Input offset current	I_{IO}			(1)	pA	
Input bias current	I_B			(1)	pA	
Output high voltage	V_{OH}	$V_{DD}-0.1$			V	$I_L = 1mA$
Output low voltage	V_{OL}			$V_{SS}+0.1$	V	$I_L = 1mA$
Voltage gain	A_V	80	120		dB	$R_L \geq 100k\Omega$
Channel supply current	$I_{DD/ch}$		40	80	μA	$R_L=\infty$, $I_O=0$
Common mode rejection ratio	CMRR	60	80		dB	
Supply voltage rejection ratio	SVRR	60	80		dB	
Common mode input voltage range	V_{ICM}	V_{SS}		V_{DD}	V	
Gain bandwidth product	GBW		550		KHz	$C_L=20pF$
Slew rate	SR		0.35		V/ μs	$C_L=20pF$

() reference value of design

Notes

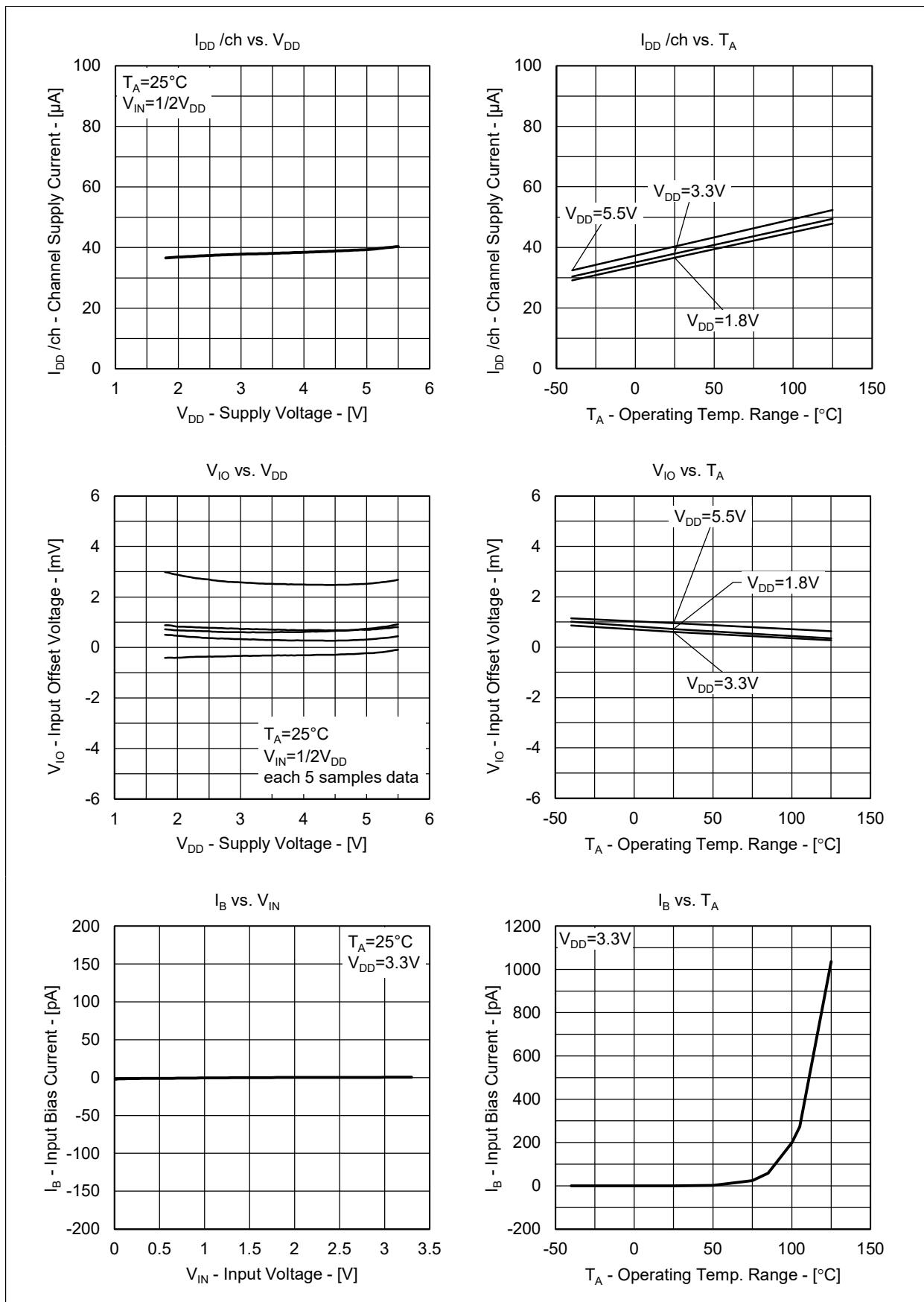
Output terminal : The over-current protection feature is not built in the output terminal of this product.

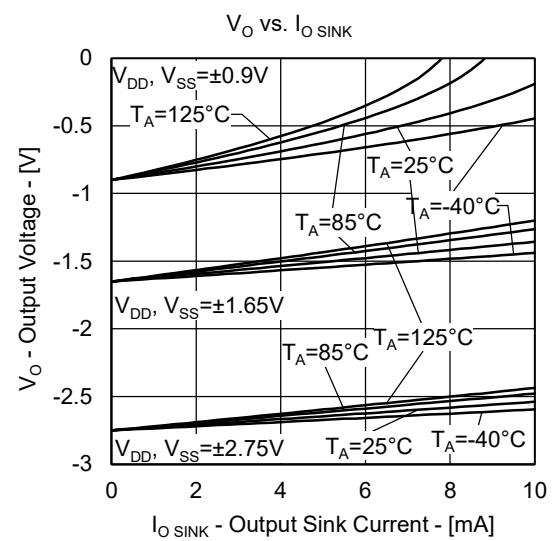
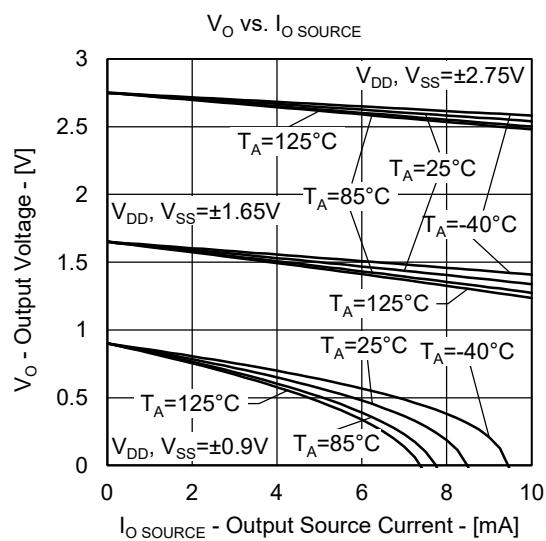
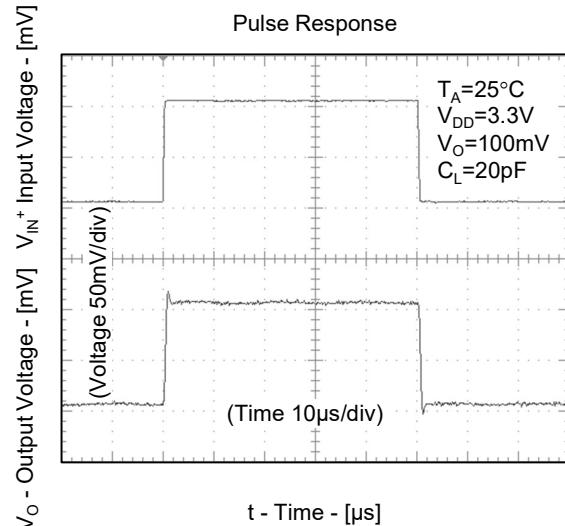
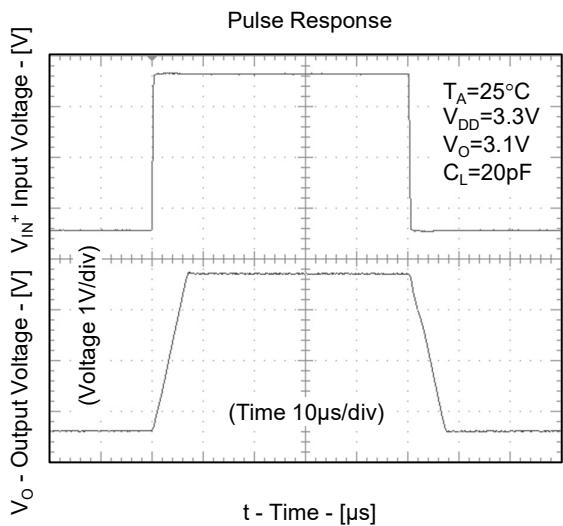
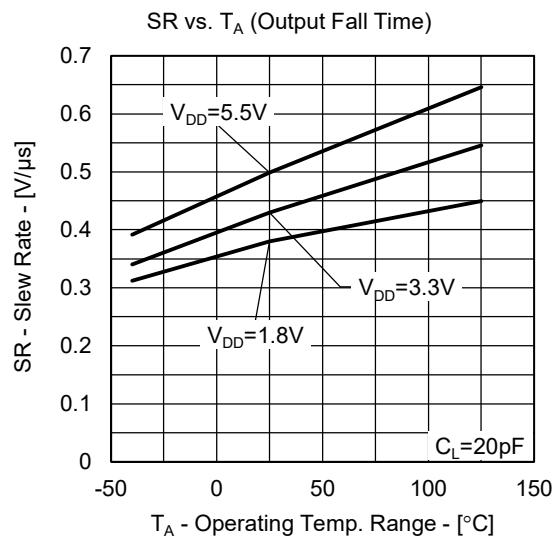
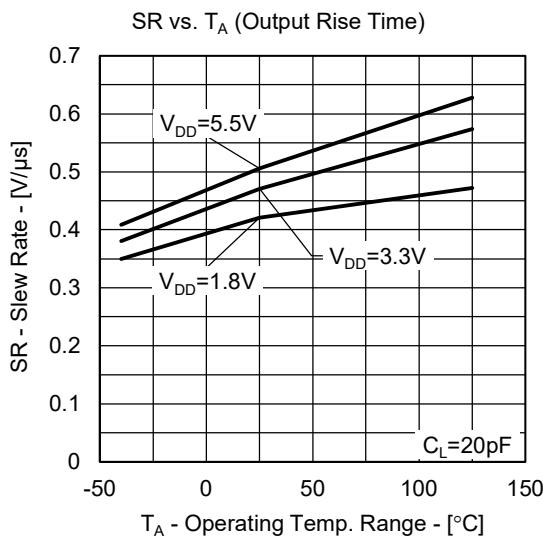
Therefore, please insert resistance to output port.

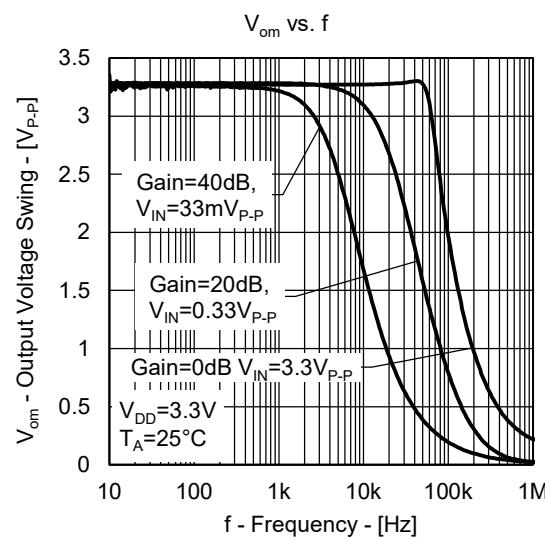
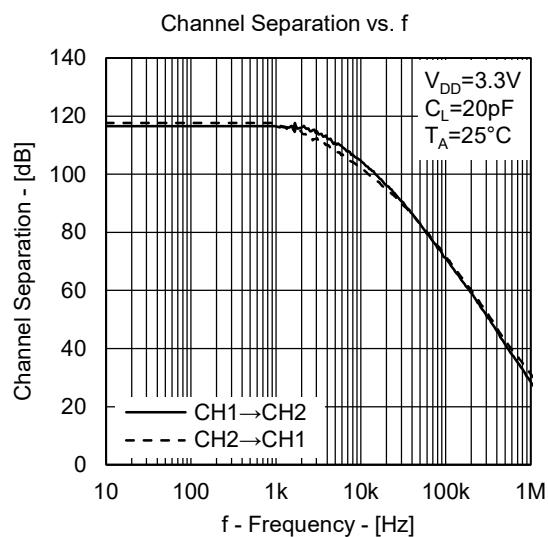
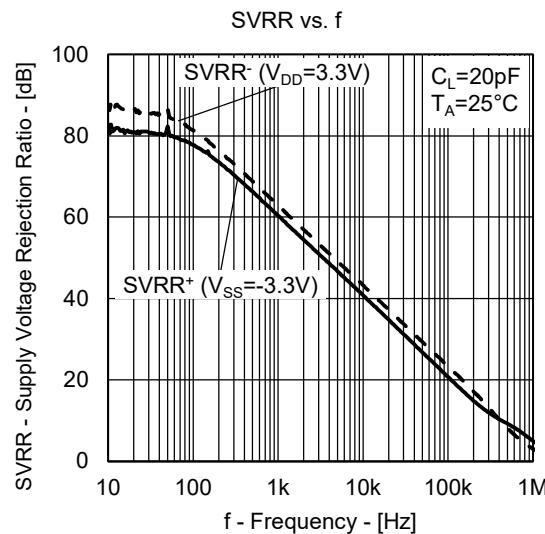
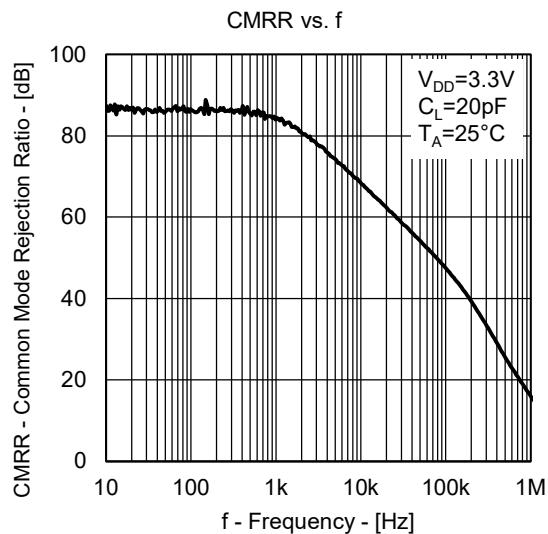
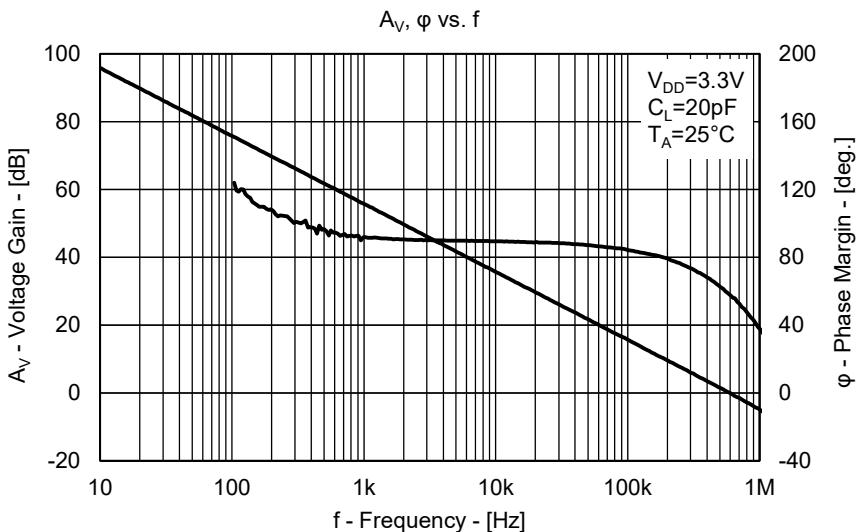
Input offset voltage : The amplifier circuit of the first block of operational amplifier.

A circuit suitable for operation near GND, and a circuit suitable for operation near +power supply. In case of input voltage of overlap point output port has a minute voltage shift or distortion.

Electrical Characteristics





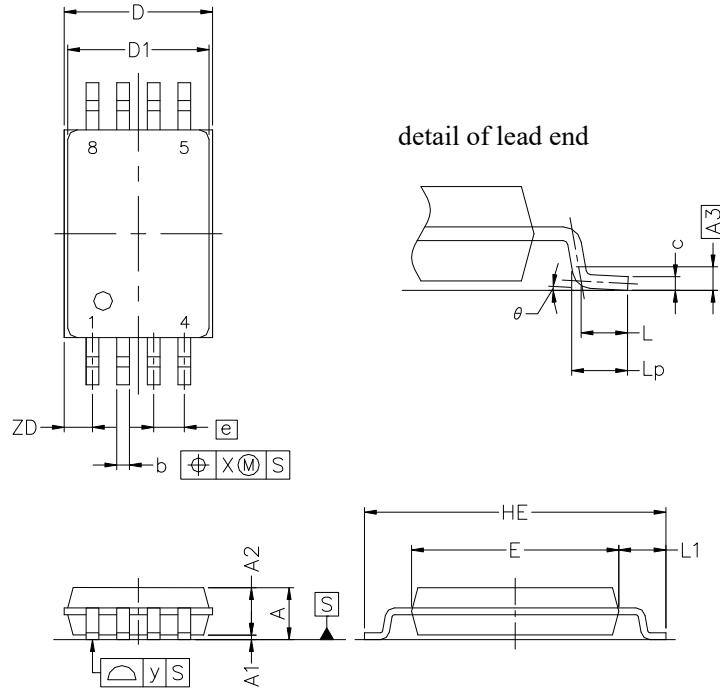


Package Dimensions

8-PIN PLASTIC TSSOP

JEITA Package code	RENESAS code	Previous code	MASS(TYP.)[g]
P-TSSOP8-0225-0.65	PTSP0008JD-A	P8GR-65-9LG	—

Unit:mm



ITEM MILLIMETERS

D	3.15 ±0.15
D1	3.00 ±0.10
E	4.40 ±0.10
HE	6.40 ±0.20
A	1.20 MAX.
A1	0.10 ±0.05
A2	1.00 ±0.05
A3	0.25
b	0.24 ^{+0.06} _{-0.05}
c	0.145 ±0.055
L	0.5
Lp	0.60 ±0.15
L1	1.00 ±0.20
θ	3° ^{+5°} _{-3°}
e	0.65
x	0.10
y	0.10
ZD	0.60

NOTE

Each lead centerline is located within 0.10 mm of its true position at maximum material condition.